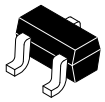
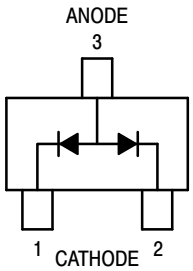
Common Anode Silicon Dual Switching Diode

M1MA141WAT1G, M1MA142WAT1G, SM1MA142WAT1G



SC-70 (SOT-323)
CASE 419
STYLE 4

This Common Anode Silicon Epitaxial Planar Dual Diode is designed for use in ultra high speed switching applications. This device is housed in the SC-70 package which is designed for low power surface mount applications.



Features

- Fast t_{rr}, < 10 ns
- Low C_D, < 15 pF
- AEC-Q101 Qualified and PPAP Capable
- S & NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS (T_A = 25 °C)

Rating	Symbol	Value	Unit
Reverse Voltage M1MA141WAT1G M1MA142WAT1G, SM1MA142WAT1G	V_R	 40 80	Vdc
Peak Reverse Voltage M1MA141WAT1G M1MA142WAT1G, SM1MA142WAT1G	V_{RM}	 40 80	Vdc
Forward Current Single Dual	I_F	 100 150	mAdc
Peak Forward Current Single Dual	I_{FM}	 225 340	mAdc
Peak Forward Surge Current M1MA141WAT1G M1MA142WAT1G, SM1MA142WAT1G	I_{FSM} (Note 1)	 500 750	mAdc

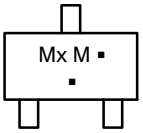
THERMAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Power Dissipation	P_D	150	mW
Junction Temperature	T_J	150	°C
Storage Temperature	T_{stg}	−55 ~ +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
1. t = 1 sec

*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

MARKING DIAGRAM



Mx = Device Code
x = N for 141
O for 142
M = Date Code*
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping†
M1MA141WAT1G	SC-70 (Pb-Free)	3,000 / Tape & Reel
NSVM1MA141WAT1G	SC-70 (Pb-Free)	3,000 / Tape & Reel
M1MA142WAT1G	SC-70 (Pb-Free)	3,000 / Tape & Reel
SM1MA142WAT1G	SC-70 (Pb-Free)	3,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25 °C)

Characteristic	Condition	Symbol	Min	Max	Unit
Reverse Voltage Leakage Current M1MA141WAT1G M1MA142WAT1G, SM1MA142WAT1G	 V_R = 35 V V_R = 75 V	I_R		 0.1 0.1	μAdc
Forward Voltage	I_F = 100 mA	V_F		1.2	Vdc
Reverse Breakdown Voltage M1MA141WAT1G, M1MA142WAT1G, SM1MA142WAT1G	I_R = 100 μA	V_R	 40 80		Vdc
Diode Capacitance	V_R = 0, f = 1.0 MHz	C_D		15	pF
Reverse Recovery Time (Figure 1)	I_F = 10 mA, V_R = 6.0 V, R_L = 100 Ω, I_{rr} = 0.1 I_R	t_{rr} (Note 2)		10	ns

2. t_{rr} Test Circuit

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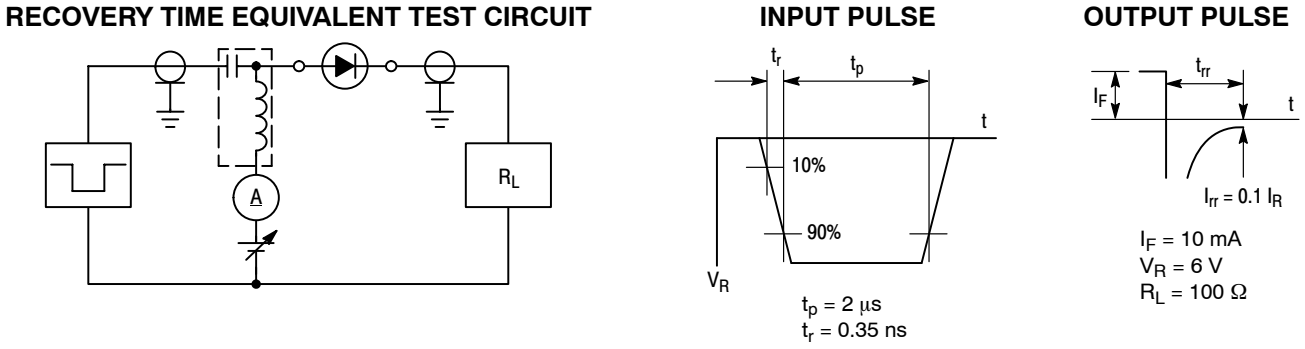


Figure 1. Recovery Time Equivalent Test Circuit

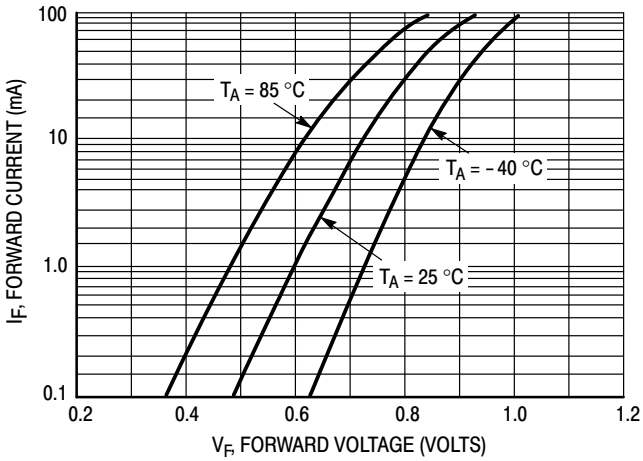


Figure 2. Forward Voltage

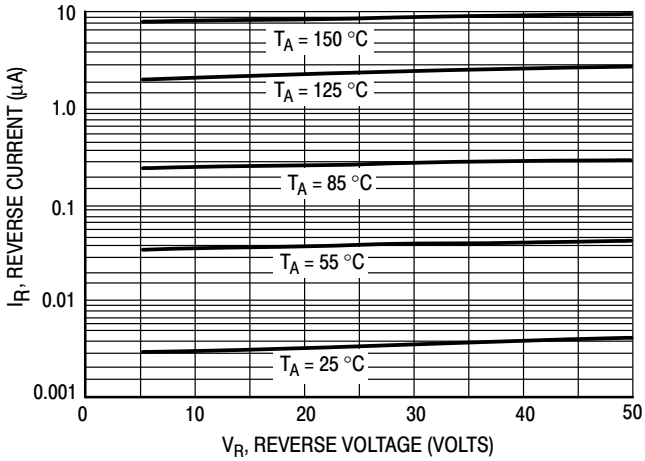


Figure 3. Reverse Current

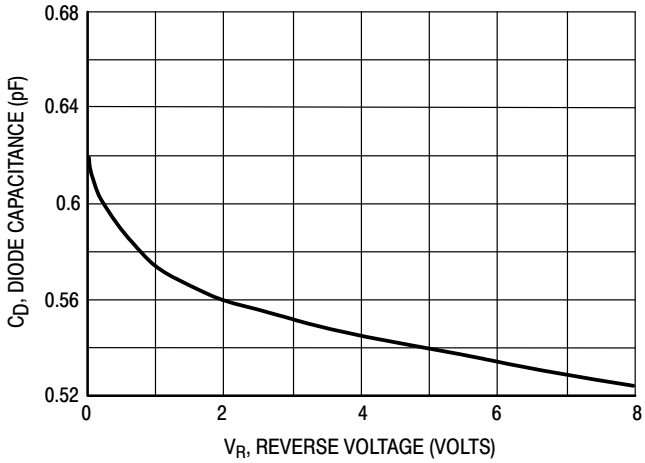


Figure 4. Diode Capacitance

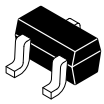
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REVISION HISTORY

Revision	Description of Changes	Date
12	Added a new OPN and edited one bullet	11/19/2025

This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.

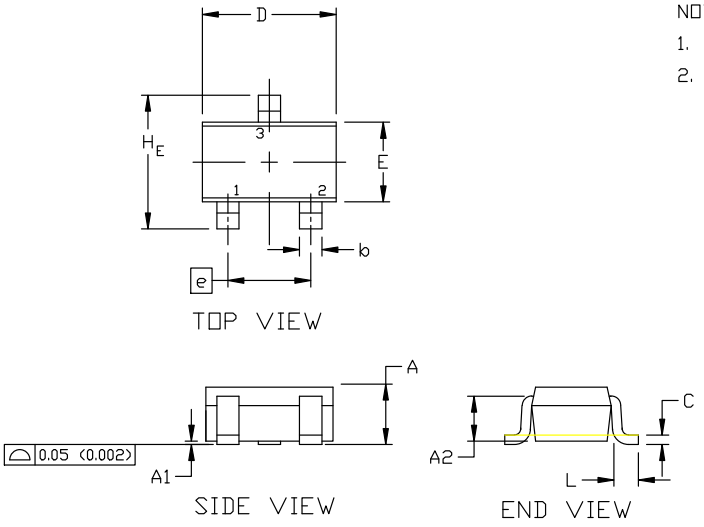
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SCALE 4:1

SC−70 (SOT−323)
CASE 419
ISSUE R

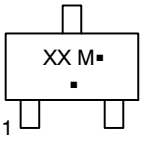
DATE 11 OCT 2022



NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH

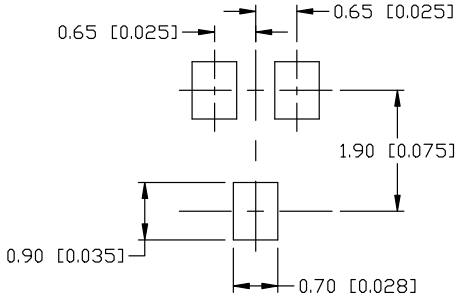
	MILLIMETERS			INCHES		
DIM	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF			0.028 BSC		
b	0.30	0.35	0.40	0.012	0.014	0.016
c	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.00	2.20	0.071	0.080	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC			0.026 BSC		
L	0.20	0.38	0.56	0.008	0.015	0.022
H_E	2.00	2.10	2.40	0.079	0.083	0.095

GENERIC MARKING DIAGRAM



XX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “▪”, may or may not be present. Some products may not follow the Generic Marking.



* For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SOLDERING FOOTPRINT

STYLE 1:
CANCELLED

STYLE 2:
PIN 1. ANODE
2. N.C.
3. CATHODE

STYLE 3:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 4:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 5:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 6:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 7:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 8:
PIN 1. GATE
2. SOURCE
3. DRAIN

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. CATHODE−ANODE

STYLE 10:
PIN 1. CATHODE
2. ANODE
3. ANODE−CATHODE

STYLE 11:
PIN 1. CATHODE
2. CATHODE
3. CATHODE

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DESCRIPTION:	**SC−70 (SOT−323)**	**PAGE 1 OF 1**

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